Pressure-tuning topological phase transitions in Kagome superconductor CsTi₃Bi₅

Wenfeng Wu^{1,2*}, Xiaocheng Bai^{3*#}, Xianlong Wang^{1,2}, Dayong Liu⁴§, Zhi Zeng,^{1,2†} and Liangjian Zou^{1,2‡}

¹ Key Laboratory of Materials Physics, Institute of Solid State Physics, HFIPS, Chinese Academy of Sciences, Hefei 230031, China

² Science Island Branch of Graduate School, University of Science and Technology of China, Hefei 230026, China

³ School of Science, Xi'an University of Posts and Telecommunications, Xi'an 710121, China

⁴ Department of Physics, Nantong University, Nantong 230026, Jiangsu, China

Abstract: Recently, the Kagome metal CsTi₃Bi₅ has exhibited several novel quantum properties similar to CsV₃Sb₅, such as nontrivial topology, double-dome superconductivity, and flat band features. However, CsTi₃Bi₅ lacks the charge-density wave (CDW) present in CsV₃Sb₅, making the study of its emergence of double-dome superconductivity a focus of research. In this work, we have identified an order parameter, the three-band Z₂ topological index, that can describe the superconducting phase diagram of CsTi₃Bi₅ under pressure. Its evolution with pressure follows the expected behavior for superconductivity. Furthermore, the results of the Fermi surface under pressure reveal the potential presence of a Lifshitz transition in the vicinity of the vanishing point of the superconducting temperature change with pressure in CsTi₃Bi₅. These results indicate that the superconducting behavior of CsTi₃Bi₅ under pressure is caused by changes in the electronic structure leading to alterations in the topological properties, provide new insights and approaches for understanding the superconducting phenomenon in Kagome metals.

Keywords: Kagome metal, Z2 topological index, superconductivity

Corresponding Author

- #xcbai@mail.ustc.edu.cn
- § dyliu@ntu.edu.cn
- † zou@theory.issp.ac.cn
- ‡ zzeng@theory.issp.ac.cn

Currently topological superconductor is the most focusing candidate for quantum computation. In the past years it has anticipated that dope- or pressure-tuning topological insulators could become topological superconductor [1–5]. However, the carrier concentration or structure variation may modulate the topology of the systems, whether it remains topological in the superconductive phase still under debated, since the doping or pressure usually tunes the system out of the topological range. Recent discovery of superconductivity in Kagome metals AV_3Sb_5 (A = Cs, Rb) has stirred great interest on the interplays among topology, superconductivity, chiral charge density wave or charge order and structural distortion, and giant anomalous Hall effect [6–15]. Especially a lot of attention has been paid on the coexistence of superconductivity and charge density wave [16–19] and associated structural distortion, obscuring the effect of interplay between the topology and superconductivity.

Meanwhile, another kind Kagome metal CsTi₃Bi₅ was also found to be superconducting [20–22]. More interestingly, CsTi₃Bi₅ in the ambient pressure is a Z₂ topological metal [21–25]. In comparison with AV₃Sb₅, CsTi₃Bi₅ does not exhibit a charge density wave (CDW) phase under ambient pressure, which allows for investigating its interplay between topological and superconducting properties without the interference of structural instability [23,26]. It also demonstrates the absence of the structural instability up to the high pressure of 40 GPa [27]. This brings CsTi₃Bi₅ great superior to AV₃Sb₅ to study the possible topological superconductor. In comparison with AV₃Sb₅, the theoretical and experimental efforts paid for understanding the properties of CsTi₃Bi₅ are far from well done, leaving many open questions, such as, under ambient pressure or small hydrostatic pressure, whether CsTi₃Bi₅ is superconducting or not [21,23,28]; whether its superconducting phase is topological superconducting state, and how the electronic states and topology evolve with increasing applied hydrostatic pressure, and so on.

In this letter, we present the systematical study of the evolutions of the structural stability, electronic states and topology of $CsTi_3Bi_5$ with the increasing hydrostatic pressure up to 40 GPa. We find that the crystal structure $CsTi_3Bi_5$ with the space group P6/mmm is stable at the pressure smaller than 40 GPa. When the pressure increases from ambient to 40 GPa, $CsTi_3Bi_5$ undergoes a series Z_2 topological states in superconducting phases and trivial states in the normal phases. The symmetry-protected surface states also appear in the Z_2 topological phases. The Fermi surfaces also experience considerably changes with increasing pressure. These results clearly suggest that $CsTi_3Bi_5$ is possibly a realistic topologically-nontrivial superconductor, and hydrostatic pressure-

could tune the topological states crossovers.

Pressure-dependent atomic structures: As shown in FIG. 1(a), the CsTi₃Bi₅ is a Kagome lattice material with the space group P6/mmm (No. 191). Specifically, Ti atoms reside in a two-dimensional plane, with one type of Bi atoms located in the same plane, while the other type of Bi atoms are perpendicular to the plane. Cs atoms serve as the cage-like framework of the material. The behavior of CsTi₃Bi₅ under pressures of 0 - 40 GPa, as mentioned earlier, does not exhibit any structural instability. Therefore, we used experimental lattice parameters to calculate its crystal structure under pressure [29], and the results are shown in FIG. 1(c). It is worth noting that, in the low-pressure range, the interlayer lattice constant *c* is more sensitive to pressure compared to the in-plane lattice constant *a*. In this stage, the volume shows the most drastic change with pressure, which is characteristic of layered materials. At higher pressures, the rate of change of both *a* and *c* with pressure becomes nearly constant.



FIG. 1 (a) Crystal structure of CsTi₃Bi₅ at 0 GPa. (b) First Brillouin zone of CsTi₃Bi₅ with high-symmetry points labeled. (c) Variation of volume and lattice constants of CsTi₃Bi₅ with pressure.

Topological Phase Diagram: Under pressure of 0 - 40 GPa, there exist continuous band gaps between ε and δ bands, as well as between the δ and γ bands in CsTi₃Bi₅ and this will be discussed further in the electronic structure section. Furthermore, CsTi₃Bi₅ possesses time-reversal and inversion symmetries. Thus, we use the Z₂ topological invariants of the ε , δ , and γ bands to characterize the topological properties of CsTi₃Bi₅, as shown in FIG. 2, and the specific positions of these three bands can be found in FIG. 4 (a). At 0 GPa, we obtain Z₂ topological invariants for the three bands as (1 1 1), see FIG. 3 (a), consistent with previous reports [22,23]. It should be noted that due to the controversy surrounding the superconductivity of $C_{s}Ti_{3}Bi_{5}$ near 0 GPa, we choose the pressure range of 1 - 40 GPa to discuss its relationship with topology. We find that within this range, at least one of the Z₂ topological invariants for these three bands is 1, indicating that the system is a Z₂ topological metal from 1 to 40 GPa. In addition, at pressures from 1 to 11.5 GPa, the Z₂ topological invariant corresponding to the γ band is 0, i.e., (1 1 0), which we refer to as topological metal II (TM II). When the pressure reaches 12 GPa, the system enters the (0 1 0) phase (TM III), and at 13 GPa, it enters the (0 1 1) phase (TM IV). The system remains in the TM III phase until the pressure increases to 34 GPa when it reenters the TM III phase and remains in this phase until 40 GPa. Our two-domed like topological phase diagram shows that the system undergoes topological phase transitions at 12 GPa and 35 GPa, which are consistent with the experimentally reported superconducting phase diagram. Moreover, the TM III phase occurring at 12 - 13 GPa and 34 - 40 GPa corresponds precisely to the pressure range in which the system is in a non-superconducting phase. This indicates that the topological phase transition induced by pressure may be a factor in the occurrence of superconductivity.



FIG. 2 The topological phase diagram of the Z_2 index of the ε , δ , and γ bands as a function of pressure. The pressure range in which the first phase exists is under debate in the superconducting phase diagram and it is separately labeled as TM I phase. The pink, yellow, and blue colors represent the TM II, TM III, and TM IV phases, respectively. Within the range of 1 - 40 GPa, the topological phase diagram can be roughly understood as having a two-dome structure.

By analyzing the product of parity at representative pressure points (5 GPa, 12.3 GPa, 30 GPa,

and 40 GPa) from 1 to 40 GPa, as shown in FIG. 3 (b) - (e). We find that as CsTi₃Bi₅ transitions from TM II to TM III, the parity of the ε band at the Γ point changes sign, leading to a change in the product of parity and a transition of the Z₂ topological invariant from 1 to 0. Similarly, as the system transitions from TM III to TM IV, the parity of the γ band at the L point changes sign, resulting in a transition of the Z₂ topological invariant from 0 to 1. When the pressure reaches around 34 GPa, the system transitions back from TM IV to TM III, and the parity of the γ band at the L point changes sign again, causing the Z₂ topological invariant to transition from 1 back to 0. We find that the TM II-TM III topological phase transition is fundamentally different from the two subsequent transitions. The two topological phase transitions experienced by the system from 12 GPa onward are both related to the changes in the product of parity at the L point. This is due to its unique electronic structure.



FIG. 3 The topological properties of the CsTi₃Bi₅ under pressures of 0, 5, 12.3, 30, and 40 GPa. (a)-(e) The parity of the ε , δ , and γ bands of CsTi₃Bi₅ at each pressure. (f) - (j) The surface states (SSs) and topologically nontrivial Dirac surface states (TDSSs) of five bands in CsTi₃Bi₅ at each pressure.

Surface States: After determining the topological classification of CsTi₃Bi₅, we have conducted a detailed study on the evolution of electronic states in surface of CsTi₃Bi₅ in different topological phases, see FIG. 3. By calculating the Green's function projection of the (001) surface spectra, at 0 GPa, the system exhibits topologically nontrivial Dirac surface states (TDSSs) between the ε and δ bands, below the Fermi level by approximately 0.7 eV. Our calculations also identify surface states (SSs) near -0.6 eV; however, these states may overlap with the pure bulk states. These results are consistent with previous angle-resolved photoemission spectroscopy (ARPES) experiments and

theoretical studies [21–23]. Under pressure, we found that the TDSSs move upward when the pressure increases to 5 GPa and completely disappear at 12.3 GPa until 40 GPa. This phenomenon corresponds to a change in the Z_2 topological invariant of the ε band from 1 to 0.

Electronic Structures: The variation of the electronic structure of CsTi₃Bi₅ as a function of pressure will be discussed. At 0 GPa, considering the spin-orbit coupling (SOC), the band structure of the system is shown in FIG. 4(a). We find that at the M point, there are Van Hove singularities (vHS1 and vHS2) appearing around 0.2 eV and 0.7 eV above the Fermi level, respectively, and there are also some band inversion points along high-symmetry paths. The density of states (DOS) reveals that Ti elements predominantly occupy the vicinity of the Fermi surface, while Cs makes negligible contributions, we also can see a high peak around 0.5 eV below the Fermi level, which is contributed by Ti atoms and has localized electrons. Subsequently, we analyze the electronic structure at different pressure points (5, 12.3, 30, and 40 GPa) in the range of 1 - 40 GPa, corresponding to different topological phases. The results show that some Dirac points in the band structure without considering SOC (see FIG. S1) are opened when SOC is considered. In addition, for the results considering SOC, there is a continuous band gap between the δ and γ bands. Under pressure, the vHS1, which is farther away from the Fermi level, changes slightly, but for the vHS2, which originally exists in the γ band at 0 GPa, it gradually moves to the δ band at 5 GPa and 12.3 GPa. At 30 GPa, the δ band at the M point is suppressed below the Fermi level, and the γ band reappears with vHS characteristics. At 40 GPa, both bands are further suppressed, and at the M point, the γ band goes below the Fermi level. In terms of the DOS under pressure, we observed a trend of downward energy shift in the peak corresponding to the flat band as the pressure increases.



FIG. 4 (a) Band structure and DOS of CsTi₃Bi₅ considering SOC at 0 GPa. The blue markings indicate Van Hove singularities, while the specific positions of α , β , ε , δ , and γ are marked in green. The purple circles represent energy bands exhibiting inverted characteristics. (b)-(e) The electronic structure of CsTi₃Bi₅ with SOC at typical pressures of 5, 12.3, 30, and 40 GPa. In terms of the DOS results, the red, green, blue, and gray lines represent the contributions from Cs, Ti, Bi atoms, and the total DOS, respectively.

The evolution of the Fermi surface at $k_z = 0$ under pressure was also investigated, as shown in FIG. 5. We found that as the pressure increases, the Fermi wave packet at the Γ point gradually shrinks and disappears around 15 GPa. Around 30 GPa, the Fermi surface at the M point disappears

due to the suppression of the δ band mentioned earlier to below the Fermi surface. At 40 GPa, further changes in the Fermi surface topology occur. These changes may lead to a Lifshitz phase transition similar to CsV₃Sb₅. From the evolution of the Fermi surface at $k_z = 0$, the pressure points where changes occur are around 15 GPa and 30 GPa, which have similarities with the pressure points of the topological phase transition described earlier. This suggests that the possible Lifshitz phase transition occurs simultaneously with the topological phase transition and the superconducting phase transition.



FIG. 5 Fermi surfaces of CsTi₃Bi₅ at pressures of 0, 5, 10, 12.3, 15, 25, 30, and 40 GPa at $k_z = 0$. The number of Fermi wave packets changes with increasing pressure in the ranges 12.5 - 15 GPa, 25 - 30 GPa, and 30 - 40 GPa.

Discussions: Here, we present a brief discussion on the relationship between topology and superconductivity in CsTi₃Bi₅. Our results indicate a correspondence between the topological phase diagram at pressures of 1 - 40 GPa and the two-domed superconducting phase diagram, suggesting the coexistence of topological and superconducting phases under pressure. Although the controversial existence of superconductivity in CsTi₃Bi₅ at 0 GPa [20,23], we infer from the aforementioned results that a superconducting phase should also be present at 0 GPa, as suggested by previous literature reporting a T_c of 4.8 K. However, further research is needed to determine whether CsTi₃Bi₅ is a topological superconductor and to investigate potential pairing mechanisms. Finally, we discuss the potential existence of a Lifshitz phase transition. We note that the sister system RbTi₃Bi₅, after K atoms doping, exhibits a similar phenomenon where the top of the δ band is tuned from above to below E_F, resembling the suppression of the δ band below the Fermi level in CsTi₃Bi₅ under pressure of around 30 GPa. We speculate that K atom doping in RbTi₃Bi₅ induces

lattice contraction, mimicking the effect of increased pressure. In fact, pressure manipulation is experimentally simpler, and we believe that pressure modulation of the Lifshitz phase transition holds promising prospects.

Summary: As a summary, we investigate the topological and electronic properties in $CsTi_3Bi_5$ under pressure using first-principles calculations. Our results reveal that the Z₂ topological invariant of the three bands near the Fermi surface exhibits a similar trend to the existing superconducting phase diagram with pressure. Additionally, the approximate location of the possible Lifshitz phase transition point coincides with the superconducting phase diagram. These findings highlight the importance of considering the topological and electronic properties in $CsTi_3Bi_5$ and call for further research in this area. This work is expected to provide valuable insights for understanding the emergence of a two-domed superconducting phase diagram in $CsTi_3Bi_5$.

References

- S. A. A. Ghorashi, J. Cano, E. Rossi, and T. L. Hughes, *Higher-Order Nodal Hinge States in Doped Superconducting Topological Insulator*, Phys. Rev. B 108, 094504 (2023).
- [2] V. K. Gangwar et al., Pressure Induced Superconducting State in Ideal Topological Insulator BiSbTe3, Phys. Scr. 96, 055802 (2021).
- [3] L. Kang, Z.-Y. Cao, and B. Wang, Pressure-Induced Electronic Topological Transition and Superconductivity in Topological Insulator Bi2Te2.1Se0.9, J. Phys. Chem. Lett. 13, 11521 (2022).
- [4] G. Dai et al., *Pressure-Induced Superconductivity in the Nonsymmorphic Topological Insulator KHgAs*, NPG Asia Mater 15, 1 (2023).
- [5] W. Zhou, B. Li, Y. Shen, J. J. Feng, C. Q. Xu, H. T. Guo, Z. He, B. Qian, Z. Zhu, and X. Xu, *Multiple Superconducting Phases Driven by Pressure in the Topological Insulator GeSb4Te7*, Phys. Rev. B 108, 184504 (2023).
- [6] Y. Wang et al., *Emergent Superconductivity in an Iron-Based Honeycomb Lattice Initiated by Pressure-Driven Spin-Crossover*, Nat Commun **9**, 1914 (2018).
- B. R. Ortiz et al., CsV3Sb5_Z2Topological Kagome Metal with a Superconducting Ground State, Phys. Rev. Lett. 125, 247002 (2020).
- [8] X. Wu et al., Nature of Unconventional Pairing in the Kagome Superconductors A V 3 Sb 5, Phys. Rev. Lett. 127, 177001 (2021).
- [9] H. Chen et al., *Roton Pair Density Wave in a Strong-Coupling Kagome Superconductor*, Nature 1 (2021).
- [10] H. LaBollita and A. S. Botana, *Tuning the van Hove Singularities in AV3Sb5 (A = K, Rb, Cs) via Pressure and Doping*, arXiv:2108.04876 [Cond-Mat] (2021).
- [11] F. Du, S. Luo, B. R. Ortiz, Y. Chen, W. Duan, D. Zhang, X. Lu, S. D. Wilson, Y. Song, and H. Yuan, *Pressure-Induced Double Superconducting Domes and Charge Instability in the Kagome Metal KV3Sb5*, Phys. Rev. B 103, L220504 (2021).
- Y.-X. Jiang et al., Unconventional Chiral Charge Order in Kagome Superconductor KV3Sb5, Nature Materials 20, 1353 (2021).
- [13] H. Tan, Y. Liu, Z. Wang, and B. Yan, Charge Density Waves and Electronic Properties of Superconducting Kagome Metals, Phys. Rev. Lett. 127, 046401 (2021).
- [14] X. Chen, X. Zhan, X. Wang, and J. Deng, *Highly Robust Reentrant Superconductivity in CsV3Sb5 under Pressure*, Chinese Physics Letters 38, 15 (2021).
- [15] S.-Y. Yang et al., Giant, Unconventional Anomalous Hall Effect in the Metallic Frustrated Magnet Candidate, KV3Sb5, Science Advances 6, eabb6003 (2020).
- [16] C. C. Zhao et al., Nodal Superconductivity and Superconducting Domes in the Topological Kagome Metal CsV3Sb5, arXiv:2102.08356 (2021).
- [17] Z. Liu et al., Charge-Density-Wave-Induced Bands Renormalization and Energy Gaps in a Kagome Superconductor RbV3Sb5, Phys. Rev. X 11, 041010 (2021).
- [18] C. Mu, Q. Yin, Z. Tu, C. Gong, H. Lei, Z. Li, and J. Luo, S-Wave Superconductivity in Kagome Metal CsV3Sb5 Revealed by 121/123Sb NQR and 51V NMR Measurements, Chinese Phys. Lett. 38, 077402 (2021).
- [19] B. R. Ortiz, P. M. Sarte, E. M. Kenney, M. J. Graf, S. M. L. Teicher, R. Seshadri, and S. D. Wilson, *Superconductivity in the Z2 Kagome Metal KV3Sb5*, Phys. Rev. Mater. 5, 034801 (2021).

- [20] H. Yang et al., Titanium-Based Kagome Superconductor CsTi3Bi5 and Topological States, arXiv:2209.03840.
- [21] Y. Hu et al., Non-Trivial Band Topology and Orbital-Selective Electronic Nematicity in a Titanium-Based Kagome Superconductor, Nat. Phys. 1 (2023).
- [22] J. Yang et al., Observation of Flat Band, Dirac Nodal Lines and Topological Surface States in Kagome Superconductor CsTi3Bi5, Nat Commun 14, 4089 (2023).
- [23] Y. Wang et al., *Flat Band and Z2 Topology of Kagome Metal CsTi3Bi5*, Chinese Phys. Lett. 40, 037102 (2023).
- [24] D. Werhahn, B. R. Ortiz, A. K. Hay, S. D. Wilson, R. Seshadri, and D. Johrendt, *The Kagomé Metals RbTi₃Bi₅ and CsTi₃Bi₅*, Zeitschrift Für Naturforschung B 77, 757 (2022).
- [25] H. Yang et al., Superconductivity and Orbital-Selective Nematic Order in a New Titanium-Based Kagome Metal CsTi3Bi5, arXiv:2211.12264.
- [26] H. Li, S. Cheng, B. R. Ortiz, H. Tan, D. Werhahn, D. Jorhendt, B. Yan, Z. Wang, S. D. Wilson, and I. Zeljkovic, *Electronic Nematicity in the Absence of Charge Density Waves in a New Titanium-Based Kagome Metal.* Nat. Physi. 19, 1591–1598 (2023)
- [27] J. Y. Nie et al., *Pressure-Induced Double-Dome Superconductivity in Kagome Metal CsTi3Bi5*, arXiv:2308.10129.
- [28] X.-W. Yi, Z.-W. Liao, J.-Y. You, B. Gu, and G. Su, Superconducting, Topological, and Transport Properties of Kagome Metals CsTi₃Bi₅ and RbTi₃Bi₅, Research 6, 0238 (2023).
- [29] B. Liu et al., Tunable Van Hove Singularity without Structural Instability in Kagome Metal, Phys. Rev. Lett. 131, 026701 (2023).